Hello, and welcome to this presentation of the STM32G4 Flexible Memory Controller. It covers all features of this interface which is used to connect external memories such as NOR Flash, NAND Flash, SRAM and PSRAM.
The FMC controller integrated in STM32G4 products provides external memory support through two memory controllers: the NOR Flash and PSRAM controller and the NAND memory controller. This enables the CPU to communicate with external memories including NOR and NAND Flash memories, PSRAM, and SRAM. This interface is fully configurable, allowing easy connection with external memories or other parallel interfaces. The benefits of the FMC controller include not only RAM and Flash memory space extension, but also the ability to interface seamlessly with most LCD controllers which support Intel 8080 and Motorola 6800 modes. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules containing embedded controllers or high-performance solutions using external controllers with dedicated acceleration.
The FMC controller offers two independent banks to support separate external memories. Each bank has an independent Chip Select and an independent configuration. Each bank features programmable timings, a configurable 8- or 16-bit data bus, and can access memory in asynchronous or burst mode for synchronous memory such as NOR Flash and PSRAM. Synchronous memory can be accessed at maximum frequency of HCLK divided by 2.
The FMC controller supports a wide variety of devices and memories. It interfaces with static memory-mapped devices including:

- Static random access memory (SRAM),
- Read-only memory (ROM),
- NOR / OneNAND Flash memory,
- PSRAM

- NAND Flash memory
  - Includes ECC hardware to check up to 8 Kbytes of data read/written
  - 3 possible interrupt sources (level, rising edge and falling edge)

- Parallel LCD modules
  - Intel 8080 and Motorola 6800

The FMC also interfaces with NAND Flash memories and supports error code correction (ECC) for up to 8 Kbytes of data read or written. Three interrupt sources can be configured to generate an interrupt when a rising edge, falling edge, or high level is detected on the NAND Flash Ready/Busy signal. Furthermore, the FMC interfaces with parallel LCD modules, supporting the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to various LCD
interfaces.
The external memory space is divided into fixed-size banks of 256 Mbytes each. Two external memory banks are dedicated to the FMC. Bank 1 is connected to the NOR/PSRAM controller and Bank 3 is connected to the NAND controller. Banks 2 and 4 are reserved.
The flexible memory controller supports non-multiplexed and multiplexed PSRAM and NOR interfaces. The non-multiplexed interface has separate address and data signals. The multiplexed interface drives the 16 address LSBs on the same pins as the 16-bit data. Thus an external address latch is required to maintain the lower part of the address while the data is transferred. This latch is embedded in some NOR and PSRAM devices. The latch enable signal is provided by the FMC through the FMC_NL output pin. This signal is named address valid, NADV, on some NOR Flash devices. FMC_NEx is one of the four chip-select signals, one per sub-bank. Regarding the PSRAM interface, the FMC accesses the right data through its byte lanes FMC_NBL[1:0].
Bank 1 is used to address up to 4 NOR Flash memories or PSRAM devices.
This bank is split into 4 NOR or PSRAM sub-banks of 64 Mbytes each with 4 dedicated Chip Selects to interface with:
- 8 or 16-bit synchronous or asynchronous NOR Flash in multiplexed or non-multiplexed mode,
- 8 or 16-bit asynchronous SRAM and ROM,
- 8 or 16-bit synchronous or asynchronous PSRAM memories.
The FMC outputs a unique Chip Select signal to each sub-bank and performs only one access at a time to an external device. The external memories are connected either to the NOR and PSRAM controller or the NAND controller, and share address, data, and control signals.
The NOR PSRAM controller allows the configuration of various timing parameters for the supported memories:

- Address setup phase: Duration of the first access phase,
- Address hold phase: Duration of the middle phase of the access cycle,
- Data setup phase: Duration of the second access phase,
- Bus turnaround phase: Duration of the bus turnaround phase,
- Clock divide ratio: Number of AHB clock cycles (or HCLK) within one memory clock cycle (or CLK),
- Data latency: Number of clock cycles to be issued to the memory before the first data transfer
- Access mode.
Bank 3 is used to interface with the NAND Flash memory. It is divided into two memory spaces: Common memory space and Attribute memory space. Both spaces are similar. The common memory space is for all NAND Flash read and write accesses, except when writing the last address byte to the NAND Flash device, where the CPU must write to the attribute memory space. This allows the implementation of the pre-wait functionality needed by certain NAND Flash memories by writing the last address byte with different timings.

Each memory space is subdivided into three sections:

- **Data section (64 Kbytes):** Used to read or write data from NAND Flash memory.
- **Command section (64 Kbytes):** Used to send a command to NAND Flash memory.
- **Address section (128 Kbytes):** Used to specify the NAND Flash memory address.

Bank 3 is used to support NAND Flash memory through two memory spaces:

- Common memory space
- Attribute memory space

Each memory space is divided into 3 subsections:

- Data section (64 Kbytes): Used to read or write data
- Command section (64 Kbytes): Used to send a command to NAND Flash memory
- Address section (128 Kbytes): Used to specify the NAND Flash memory address.
The FMC generates the appropriate signals to drive NAND Flash memory. The address, data and control signals are shared with the NOR and PSRAM controller. The command latch enable (or CLE) and address latch enable (or ALE) signals of the NAND Flash memory device are driven by address signals from the FMC controller connected to Address line 16 and Address line 17 respectively. The ALE is active when writing to the address section and the CLE is active when writing to command section.
The FMC NAND memory controller supports the following features:

- ECC hardware acceleration for read and write operations ranging from 256 to 8192 bytes
- 3 interrupt sources for NAND bank
  - Rising edge
  - Falling edge
  - Level of the external memory Ready/nBusy output pin
- Wait feature management
  - The controller waits for the NAND Flash memory to be ready (Ready/nBusy signal high), before starting a new access

The MPU memory attribute of the FMC NAND bank must be configured as “Device”
Each common and attribute memory space can be configured with different timings for the NAND Flash’s command, address write, and data read/write accesses. The attribute memory space is used for the last address write access if the timing must differ from that of previous accesses in case of Ready/Busy management. Otherwise only common space is needed.

Four parameters are used to define the number of HCLK cycles for the different phases of any NAND Flash access:

• Setup time,
• Wait time,
• Hold time,
• Data bus HiZ time.
<table>
<thead>
<tr>
<th>Interrupt event</th>
<th>Description</th>
</tr>
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<tbody>
<tr>
<td>Rising edge</td>
<td>Rising edge has been detected on FMC_INT pin</td>
</tr>
<tr>
<td>Falling edge</td>
<td>Falling edge has been detected on FMC_INT pin</td>
</tr>
<tr>
<td>High level</td>
<td>High level has been detected on FMC_INT pin</td>
</tr>
</tbody>
</table>

The NAND controller offers 3 interrupt sources: rising edge, falling edge, and high level detection on the FMC_INT pin when it is connected to the Ready/Busy signal from the NAND Flash memory.
The FMC is active in Run, Sleep, Low-power run and Low-power sleep modes.  
A FMC interrupt can cause the device to exit Sleep or Low-power sleep mode.  
In Stop 0 and Stop 1 modes, the FMC is frozen, and the content of its registers is kept.  
In Standby or Shutdown mode, the FMC is powered-down and it must be reinitialized afterwards.
Wearable applications require low-power management together with a high-quality user interface. This can be achieved using the STM32G4 FMC to connect the display thanks to its flexibility and widely programmable parameters to interface with LCD modules. In addition the FMC or Quad-SPI interface may be used to access an external Flash memory containing all of the graphical content needed such as background images, high-resolution icons, or fonts to support multiple languages. Additional audio data for ringtones can also benefit from the large space offered by the external Flash memory.

Thank you.